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The technical content of this CMOSIS / AWAIBA document is still valid.

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CMV12000

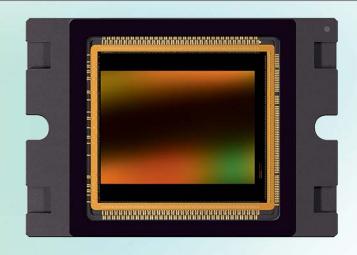
12MP high speed global shutter image sensor

SENSOR DESCRIPTION

The CMV12000 is a global shutter CMOS image sensor with 4096 by 3072 pixels in a APS-C optical format supporting super HD imaging (4k). The image array consists of 5.5 um by 5.5 um pipelined global shutter pixels, which allow exposure during read out while performing CDS operation reducing fixed pattern and dark noise significantly. The CMV12000 has 64 12-bit digital LVDS outputs (serial) each running at 600 Mbps. The image sensor also integrates a programmable gain amplifier and offset regulation. Each channel runs at 600 Mbps maximum, which results in 300 fps frame rate at full resolution in 10-bit mode. Higher frame rates can be achieved in rowwindowing mode or row-subsampling mode. All operation modes are all programmable using a SPI interface. A programmable on-board sequencer generates all internal exposure and read out timings. External triggering and exposure programming is also possible. Extended optical dynamic range can be achieved by multiple integrated high dynamic range modes. A 12-bit per pixel mode is available at reduced frame rates.

APPLICATION FIELDS

- Machine vision
- Motion control
- Traffic monitoring
- · High speed inspection
- Broadcast



SENSOR FEATURES

- Pipelined global shutter with CDS
- 4096 (H) x 3072 (V) active pixels on a 5.5 µm pitch
- 300 frames/s at full resolution in 10 bit mode
- 132 frames/s at full resolution in 12 bit mode
- ROI windowing capability (up to 32 separate ROIs - row based only)
- · X-Y mirroring function
- 64 LVDS-outputs @ 600 Mbps multiplexable to 32, 16, 8, 4 and 2 at reduced frame rate
- Multiple High Dynamic Range modes supported up to 90 dB
- · On chip temperature sensor
- On chip timing generation
- SPI-control
- On chip pixel averaging (increased frame rate and dynamic range)
- 3.3 V signaling
- Monochrome and Bayer (RGB) configuration
- Ceramic 237-pins µPGA package (47 mm x 33.8 mm)
- 2 sided AR-coated cover glass lid





CMV12000

12MP high speed global shutter image sensor

SENSOR SPECIFICATIONS

Specification Value

Part status Pre-Production

Resolution 12MP - 4096 (H) x 3072 (V)

Pixel size $5.5 \times 5.5 \ \mu m^2$ Optical Format APS-like

Shutter Type Pipelined global shutter

with true CDS

Frame Rate 300 fps (10 bit)

132 fps (12 bit)

Output Interface 64 LVDS @ 600 Mbps

Sensitivity 4.64 V/lux.s

Conversion gain 0.075 LSB/e

Full well charge 13500 e
Dark noise 13 e- (RMS)

Dynamic range 60 dB

SNR max 41.3 dB

Parasitic light sensitivity 1/50000

Extended dynamic range Yes, up to 90 dB Dark current 125 e-/s (25°C)

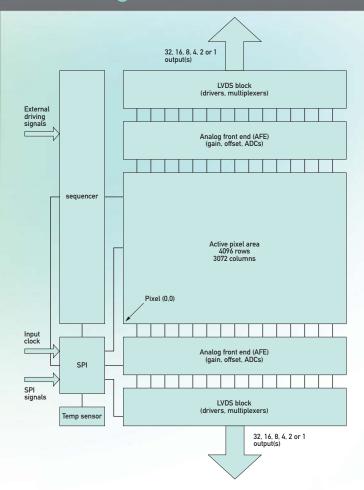
Fixed pattern noise < 1 LSB (<0.1 % of full swing)

Chroma Mono and RGB Supply voltage 1.8 V / 3.3 V Power 4200 mW

Operating temperature -30°C to +70°C (TBC)

range

RoHS compliance Yes (TBC) Package 237 pins μ PGA



ORDERING INFORMATION

CMV12000	Description
CMV12000-2E5M1PA	Monochrome version
CMV12000-2E5M1PN	Monochrome version
	with removeable glass lid
CMV12000-2E12M1PA	Monochrome version
	NIR enhanced
CMV12000-2E5C1PA	RGB Bayer Color version